



Part: L4004D3
Series: Teccor® Sensitive Triac Devices
Technology: Triacs

PARAMETERS

Package Type	Pkg Type	Surface Mount
Mount Method	Mount	Surface Mount
Critical Rate-of-rise of On-state Current	di/dt (A/ μ s)	50
Critical rate-of-rise of off-state voltage	dv/dt @ 100°C (V/ μ s)	25
Critical rate-of-rise of off-state voltage	dv/dt @ 125°C (V/ μ s)	0
Critical Rate-of-rise of Commutation Voltage of a Triac (commutating dv/dt)	dv/dt(c) TYP (V/ μ s)	0
Repetitive Peak off-state Current	I _{DRM} @ 100°C max (mA)	0.0000
Repetitive Peak off-state Current	I _{DRM} @ 110°C MAX (mA)	0.2000
Repetitive Peak off-state Current	I _{DRM} @ 125°C max (mA)	0.0000
Repetitive Peak off-state Current	I _{DRM} @ 25°C max (mA)	0.0100
Gate Trigger Current - Q4	I _{GT} Q4 TYP (mA)	0
Peak gate trigger current	I _{GTM} (A)	1.2000
RMS Surge (Non-repetitive) On-state Fusing Current	I ² t (A ² Sec)	6.6000
Average Gate Power Dissipation	P _{G(AV)} (Watts)	0.3000
Peak Gate Power Dissipation	P _{GM} (Watts)	15
Package Size / Form Factor	Size	TO-252
Gate-controlled Turn-on time	T _{GT} TYP (μ s)	2.8000
Maximum Gate Trigger Voltage	V _{GT} MAX @ 125°C (V)	0.2000
Gate Trigger Voltage	V _{GT} MAX @ 25°C (V)	2.0000
Peak on-state voltage a maximum rated RMS current	V _{TM} (V)	1.6000
Maximum On-state Current	I _{T(RMS)} MAX (A)	4
Repetitive Peak Off-state Voltage	V _{DRM} MIN (V)	400
Gate Trigger Current - Q1	I _{GT} Q1 MAX (mA)	3
Gate Trigger Current - Q2	I _{GT} Q2 MAX (mA)	3
Gate Trigger Current - Q3	I _{GT} Q3 MAX (mA)	3
Gate Trigger Current - Q4	I _{GT} Q4 MAX (mA)	3
Maximum Holding Current	I _H MAX (mA)	5
Surge (Non-repetitive) On-state current	I _{TSM} @ 60Hz (A)	40
Surge (Non-repetitive) On-state current	I _{TSM} @ 50Hz (A)	33

